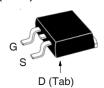


Polar3[™] HiperFET[™] **Power MOSFETs**

IXFA22N60P3 IXFP22N60P3 IXFQ22N60P3 IXFH22N60P3

N-Channel Enhancement Mode Avalanche Rated Fast Intrinsic Rectifier

TO-263 AA (IXFA)



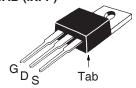


Test Conditions	Maximum Ratings		
$T_J = 25^{\circ}C$ to $150^{\circ}C$	600	V	
$T_J = 25$ °C to 150°C, $R_{GS} = 1M\Omega$	600	V	
Continuous	± 30	V	
Transient	± 40	V	
$T_{c} = 25^{\circ}C$	22	Α	
$T_{\rm C} = 25^{\circ}$ C, Pulse Width Limited by $T_{\rm JM}$	55	Α	
$T_{c} = 25^{\circ}C$	11	Α	
$T_{c} = 25^{\circ}C$	400	mJ	
$I_{_{\mathrm{S}}} \le I_{_{\mathrm{DM}}}, \ V_{_{\mathrm{DD}}} \le V_{_{\mathrm{DSS}}}, \ T_{_{\mathrm{J}}} \le 150^{\circ}\mathrm{C}$	35	V/ns	
T _c = 25°C	500	W	
	-55 +150	°C	
	150	°C	
	-55 +150	°C	
1.6mm (0.062in.) from Case for 10s Plastic Body for 10 seconds	300 260	°C °C	
Mounting Force Mounting Torque	1065 / 2.214.6 1.13 / 10	N/lb. Nm/lb.in.	
TO-263 TO-220 TO-3P TO-247	2.5 3.0 5.5 6.0	9 9 9	
	$T_{_{J}}=25^{\circ}\text{C to }150^{\circ}\text{C}$ $T_{_{J}}=25^{\circ}\text{C to }150^{\circ}\text{C}, R_{_{GS}}=1\text{M}\Omega$ Continuous Transient $T_{_{C}}=25^{\circ}\text{C}$ $T_{_{C}}=25^{\circ}\text{C}, \text{ Pulse Width Limited by }T_{_{JM}}$ $T_{_{C}}=25^{\circ}\text{C}$ $T_{_{C}}=25^{\circ}\text{C}$ $I_{_{S}}\leq I_{_{DM}}, V_{_{DD}}\leq V_{_{DSS}}, T_{_{J}}\leq 150^{\circ}\text{C}$ $T_{_{C}}=25^{\circ}\text{C}$ $1.6\text{mm (0.062in.) from Case for 10s}$ Plastic Body for 10 seconds $Mounting \text{ Force}$ $Mounting \text{ Torque}$ $T0-263$ $T0-220$ $T0-3P$	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	

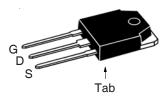
			teristic Typ.	Values Max.	
BV _{DSS}	$V_{GS} = 0V, I_{D} = 1mA$	600			V
V _{GS(th)}	$V_{DS} = V_{GS}$, $I_{D} = 1.5 \text{mA}$	3.0		5.0	V
I _{GSS}	$V_{GS} = \pm 30V, V_{DS} = 0V$			±100	nA
I _{DSS}	$V_{DS} = V_{DSS}, V_{GS} = 0V$ $T_{J} = 125^{\circ}C$			25 1.25	μA mA
R _{DS(on)}	$V_{GS} = 10V, I_{D} = 0.5 \cdot I_{D25}, Note 1$			360	mΩ

600V **22A** D25 $360 m\Omega$ $\boldsymbol{R}_{\text{DS(on)}}$

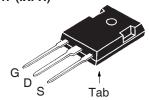
TO-220AB (IXFP)



TO-3P (IXFQ)



TO-247 (IXFH)



G = Gate D = Drain S = SourceTab = Drain

Features

- Fast Intrinsic Rectifier
- Avalanche Rated
- Low R_{DS(ON)} and Q_G
 Low Package Inductance

Advantages

- High Power Density
- Easy to Mount
- Space Savings

Applications

- Switch-Mode and Resonant-Mode **Power Supplies**
- DC-DC Converters
- Laser Drivers
- AC and DC Motor Drives
- Robotics and Servo Controls



Symbol Test Conditions Char (T ₁ = 25°C Unless Otherwise Specified) Min.		racteristic Values		
g_{fs}	$V_{DS} = 20V, I_{D} = 0.5 \cdot I_{D25}, \text{ Note 1}$	14	24	S
C _{iss}			2600	pF
C _{oss}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		265	pF
C _{rss}			3.4	pF
R_{Gi}	Gate Input Resistance		1.3	Ω
t _{d(on)}	Resistive Switching Times		28	ns
t,	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		17	ns
t _{d(off)}	$R_{\rm g} = 10$ (External)		54	ns
t,			19	ns
$Q_{g(on)}$			38	nC
Q _{gs}	$V_{GS} = 10V$, $V_{DS} = 0.5 \cdot V_{DSS}$, $I_{D} = 0.5 \cdot I_{D25}$		10	nC
\mathbf{Q}_{gd}			11	nC
R _{thJC}				0.25 °C/W
R _{thCS}	TO-220 TO-247 & TO-3P		0.50 0.25	°C/W
	10-241 & 10-3F		0.20	C/ VV

Source-Drain Diode

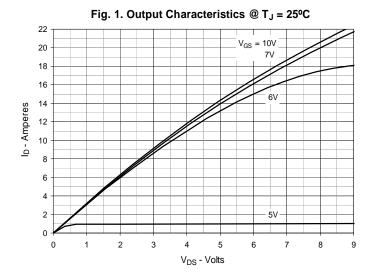
SymbolTest ConditionsCh $(T_J = 25^{\circ}C \text{ Unless Otherwise Specified})$ Min.			racteristic Typ.	Values Max.	
I _s	$V_{GS} = 0V$			22	Α
I _{sm}	Repetitive, Pulse Width Limited by $T_{_{JM}}$			88	Α
V _{SD}	$I_F = I_S$, $V_{GS} = 0V$, Note 1			1.4	V
t _{rr}	$I_{\rm F} = 11A$, -di/dt = 100A/ μ s			250	ns
I _{RM}	$V_{R} = 100V, V_{GS} = 0V$		8.0		Α
$\mathbf{Q}_{_{\mathrm{RM}}}$	$\int V_{R} = 100V, V_{GS} = 0V$		0.8		μC

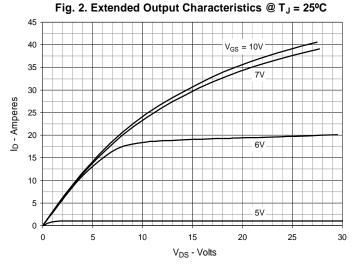
Note 1. Pulse test, $t \le 300\mu s$, duty cycle, $d \le 2\%$.

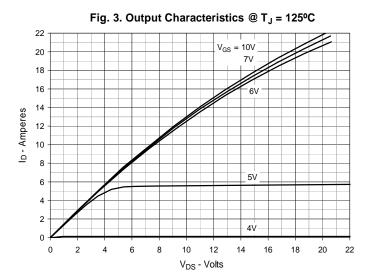
PRELIMINARY TECHNICAL INFORMATION

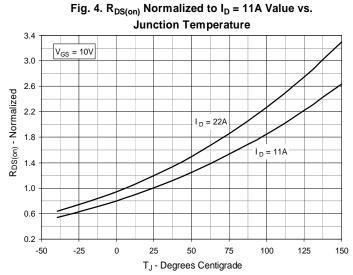
The product presented herein is under development. The Technical Specifications offered are derived from data gathered during objective characterizations of preliminary engineering lots; but also may yet contain some information supplied during a pre-production design evaluation. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

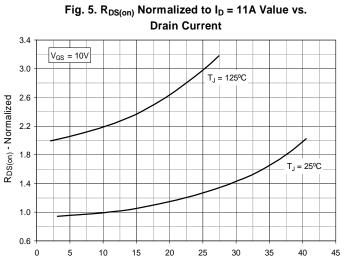




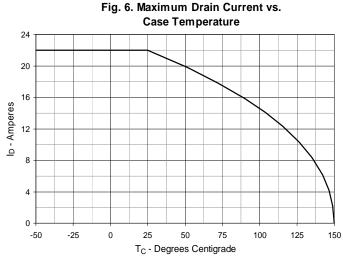




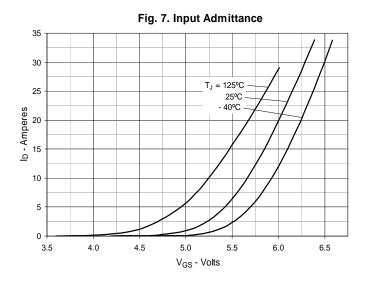


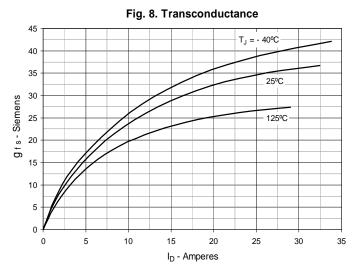


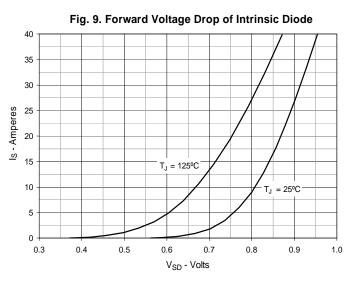
 I_D - Amperes

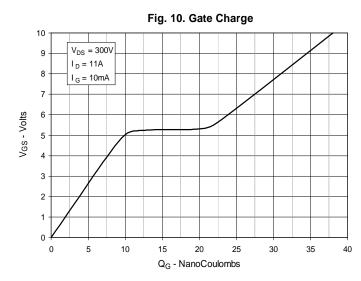


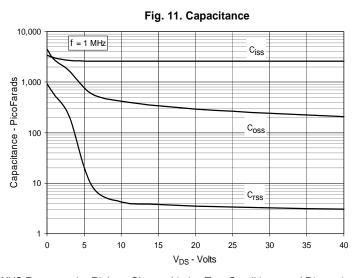


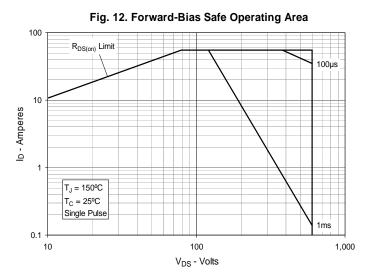












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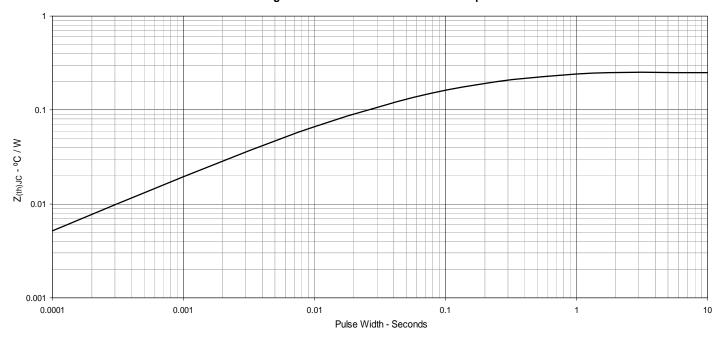


Fig. 13. Maximum Transient Thermal Impedance





Terminals: 1 - Gate 3 - Source

	SYM	INCHES		MILLIMETERS			
		MIN	MAX	MIN	MAX		
	Α	.170	.190	4.32	4.83		
	b	.025	.040	0.64	1.02		
	b1	.045	.065	1.15	1.65		
	C	.014	.022	0.35	0.56		
	D	.580	.630	14.73	16.00		
	E	.390	.420	9.91	10.66		
	е	.100 BSC		2.54	BSC		
	F	.045	.055	1.14	1.40		
	H1	.230	.270	5.85	6.85		

 D
 .580
 .630
 14.73
 16.00

 E
 .390
 .420
 9.91
 10.66

 e
 .100 BSC
 2.54 BSC

 F
 .045
 .055
 1.14
 1.40

 H1
 .230
 .270
 5.85
 6.85

 J1
 .090
 .110
 2.29
 2.79

 k
 0
 .015
 0
 0.38

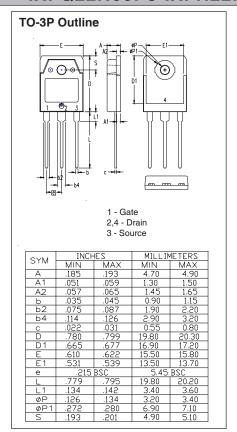
 L
 .500
 .550
 12.70
 13.97

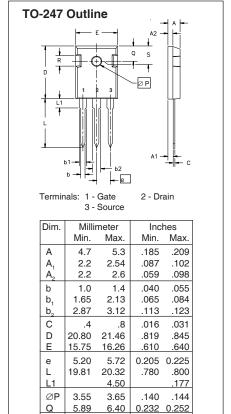
 L1
 .110
 .230
 2.79
 5.84

 ØP
 .139
 .161
 3.53
 4.08

 O
 .100
 .255
 2.54
 3.18

TO-263 Outline 1 - Gate 2,4 - Drain 3 - Source | 1 - William | 1 - Wil





R

4.32

6.15 BSC

5.49

.170

242 BSC

.216

 $\ensuremath{\mathsf{IXYS}}$ Reserves the Right to Change Limits, Test Conditions, and Dimensions.